

TPS565208 4.5-V to 17-V Input, 5-A Synchronous Step-Down Voltage Regulator in SOT-23

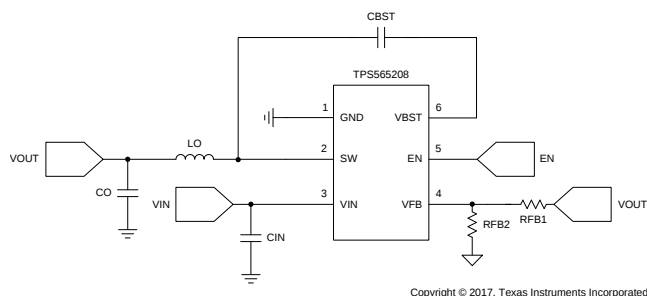
1 Features

- 5-A Maximum Output Current
- Integrated 31-mΩ and 16-mΩ FETs
- D-CAP2™ Mode Control with Fast Transient Response
- Input Voltage Range: 4.5 V to 17 V
- Output Voltage Range: 0.76 V to 7 V
- Continuous Current Mode
- 500-kHz Switching Frequency
- Low Shutdown Current of Less than 1 μA
- 1% Feedback Voltage Accuracy
- Startup from Pre-biased Output Voltage
- Cycle-by-Cycle Current Limit
- Hiccup-mode Overcurrent Protection
- Non-Latch UVP and TSD Protections
- Fixed Soft Start: 1.0 ms
- Create a Custom Design Using the TPS565208 With the [WEBENCH® Power Designer](#)

2 Applications

- Digital TV Power Supply
- High Definition Blu-ray™ Disc Players
- Networking Home Terminal
- Digital Set Top Box (STB)
- Surveillance

Simplified Schematic



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3 Description

The TPS565208 is a simple, easy-to-use, 5-A synchronous step-down converter in SOT-23 package.

The device is optimized to operate with minimum external component count and also optimized to achieve low standby current.

This switch mode power supply (SMPS) device employs D-CAP2™ mode control, which provides fast transient response and requires no external compensation components. D-CAP2™ also allows the use of low-equivalent series resistance (ESR) specialty polymer capacitors and ceramic capacitors.

The TPS565208 is available in a 6-pin 1.6-mm × 2.9-mm SOT (DDC) package, and operates over a –40°C to 125°C junction temperature range.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TPS565208	DDC (6)	1.60 mm × 2.90 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

TPS565208 Load Regulation

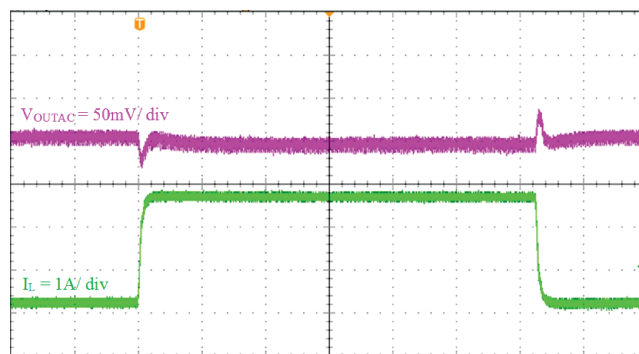


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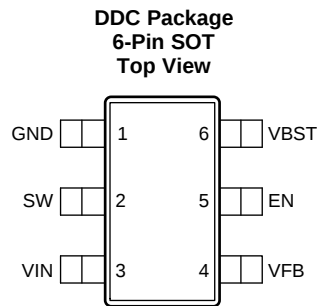
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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (September 2017) to Revision B	Page
• Added Tape and Reel information with improved yield.	20
Changes from Original (September 2017) to Revision A	Page
• Initial public release.	1

5 Pin Configuration and Functions



Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		
GND	1	—	Ground pin. Source terminal of low-side power NFET as well as the ground terminal for controller circuit. Connect sensitive VFB to this GND at a single point.
SW	2	O	Switch node connection between high-side NFET and low-side NFET.
VIN	3	I	Input voltage supply pin. The drain terminal of high-side power NFET.
VFB	4	I	Converter feedback input. Connect to output voltage with feedback resistor divider.
EN	5	I	Enable input control. Active high and must be pulled up to enable the device.
VBST	6	O	Supply input for the high-side NFET gate drive circuit. Connect 0.1 μ F capacitor between VBST and SW pins.

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Input voltage	VIN, EN	−0.3	19	V
	VBST	−0.3	25	V
	VBST (10 ns transient)	−0.3	27	V
	VBST (vs SW)	−0.3	6.5	V
	VFB	−0.3	6.5	V
	SW	−2	19	V
	SW (10 ns transient)	−3.5	21	V
Operating junction temperature, T _J		−40	150	°C
Storage temperature, T _{stg}		−55	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

		VALUE	UNIT
V _(ESD) Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±4000	V
	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1500	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V _{IN}	Supply input voltage range	4.5		17	V
V _I	Input voltage range	VBST	−0.1	23	V
		VBST (10 ns transient)	−0.1	26	
		VBST (vs SW)	−0.1	6.0	
		EN	−0.1	17	
		VFB	−0.1	5.5	
		SW	−1.8	17	
		SW (10 ns transient)	−3.5	20	
T _J	Operating junction temperature	−40		125	°C

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TPS565208	UNIT
		DDC (SOT)	
		6 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	95.9	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	35.6	°C/W
R _{θJB}	Junction-to-board thermal resistance	16.4	°C/W
ψ _{JT}	Junction-to-top characterization parameter	1.4	°C/W
ψ _{JB}	Junction-to-board characterization parameter	16.4	°C/W

- (1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

6.5 Electrical Characteristics

 $T_J = -40^{\circ}\text{C}$ to 125°C , $V_{IN} = 12\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY CURRENT						
I _{VIN}	Operating – non-switching supply current	V _{IN} current, EN = 5 V, V _{FB} = 1 V		590	780	μA
I _{VINSDN}	Shutdown supply current	V _{IN} current, EN = 0 V		0.8	5	μA
LOGIC THRESHOLD						
V _{ENH}	EN high-level input voltage		1.6			V
V _{ENL}	EN low-level input voltage			0.8		V
R _{EN}	EN pin resistance to GND	V _{EN} = 12 V	120	245	400	kΩ
V _{FB} VOLTAGE AND DISCHARGE RESISTANCE						
V _{FBTH}	V _{FB} threshold voltage		753	760	767	mV
I _{VFB}	V _{FB} input current	T _A = 25°C, V _{FB} = 0.8 V		0	±0.1	μA
MOSFET						
R _{DS(on)h}	High-side switch resistance	T _A = 25°C, V _{BST} – V _{SW} = 5.5 V		31		mΩ
R _{DS(on)l}	Low-side switch resistance	T _A = 25°C		16		mΩ
CURRENT LIMIT						
I _{OCL}	Current limit		5.3	6.7	8	A
THERMAL SHUTDOWN						
T _{SDN}	Thermal shutdown threshold ⁽¹⁾	Shutdown temperature		172		°C
		Hysteresis		38		
ON-TIME TIMER CONTROL						
t _{OFF(MIN)}	Minimum off time	V _{FB} = 0.61 V		236	280	ns
SOFT START						
t _{SS}	Soft-start time	Internal soft-start time		1.0		ms
FREQUENCY						
F _{SW}	Switching frequency	V _{IN} = 12 V, V _{OUT} = 5 V, CCM mode		500		kHz
OUTPUT UNDERVOLTAGE AND OVERVOLTAGE PROTECTION						
V _{UVP}	Output UVP threshold	Hiccup detect (H > L)		65		%
T _{HICCUP_WAIT}	Hiccup on time			1.8		ms
T _{HICCUP_RE}	Hiccup time before restart			14.9		ms
UVLO						
UVLO	UVLO threshold	Wake up VIN voltage		4.0	4.3	V
		Shutdown VIN voltage	3.3	3.6		
		Hysteresis VIN voltage ⁽¹⁾		0.4		

(1) Not production tested.

6.6 Typical Characteristics

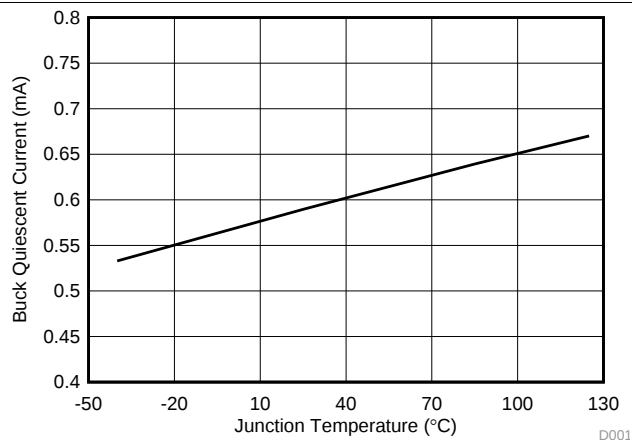
 $V_{IN} = 12\text{ V}$ (unless otherwise noted)


Figure 1. TPS565208 Supply Current vs Junction Temperature

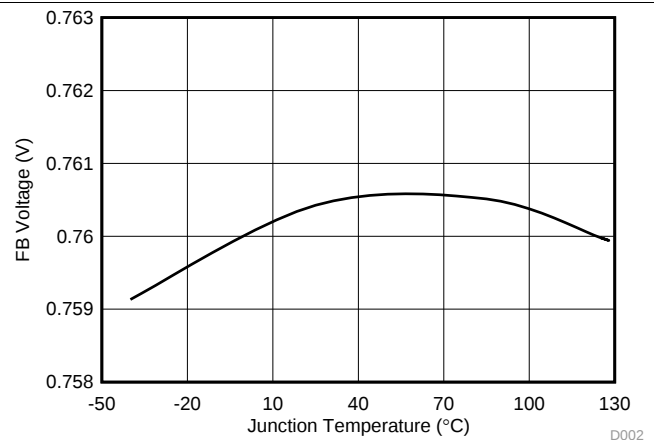


Figure 2. VFB Voltage vs Junction Temperature

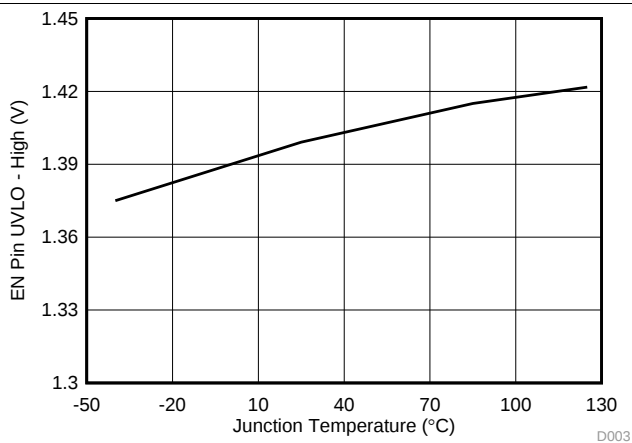


Figure 3. EN Pin UVLO Low Voltage vs Junction Temperature

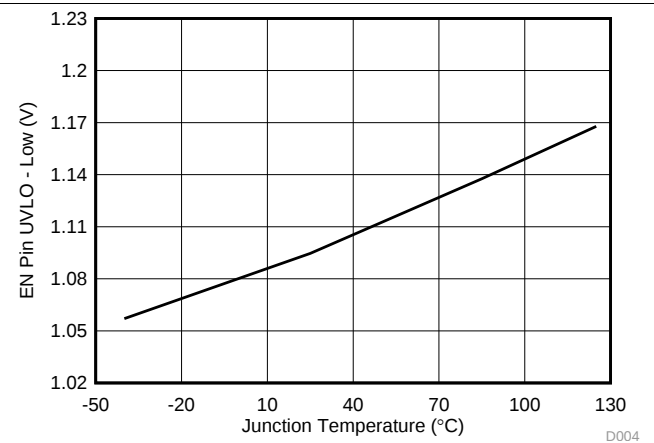


Figure 4. TPS565208 EN Pin UVLO High Voltage vs Junction Temperature

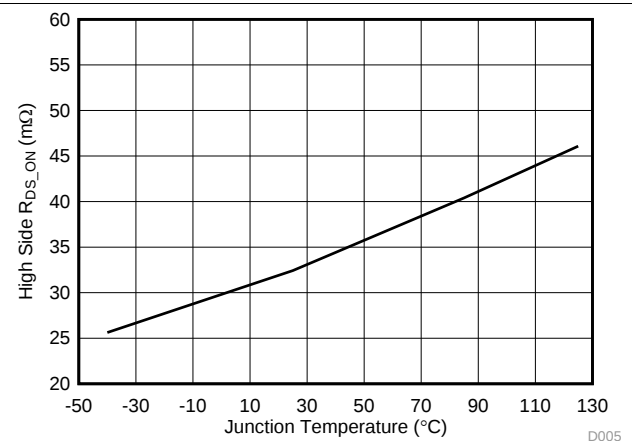


Figure 5. High-Side R_{ds-on} vs Junction Temperature

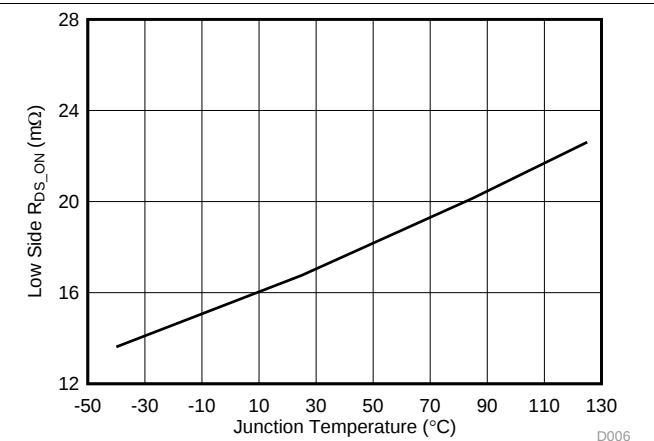


Figure 6. Low-Side R_{ds-on} vs Junction Temperature

Typical Characteristics (continued)

$V_{IN} = 12\text{ V}$ (unless otherwise noted)

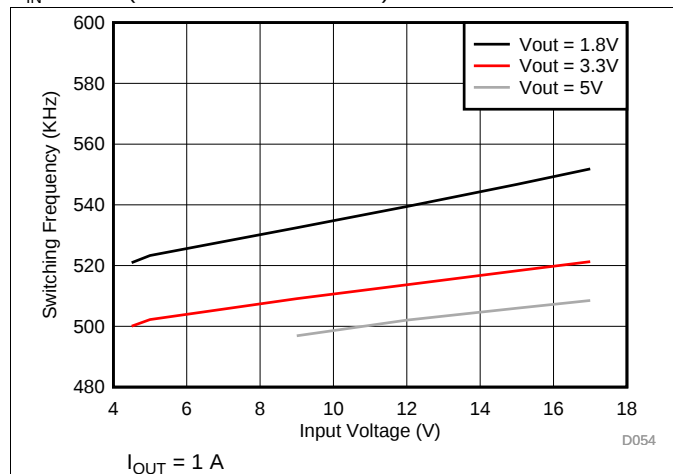


Figure 7. TPS565208 Switching Frequency vs Input Voltage

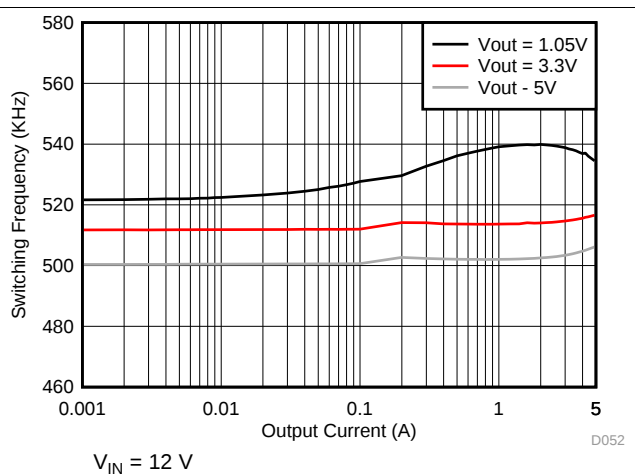


Figure 8. TPS565208 Switching Frequency vs Output Current

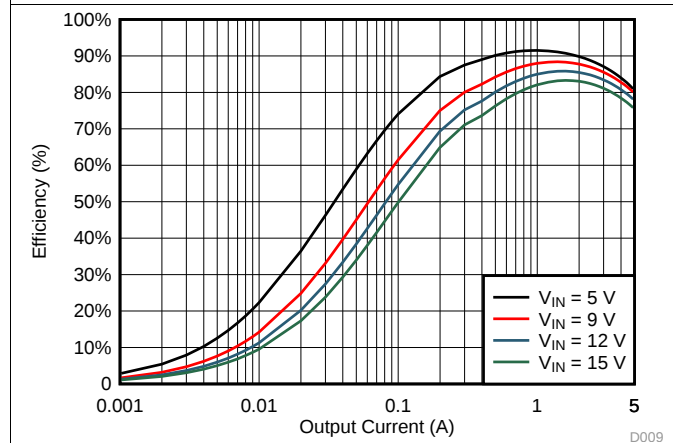


Figure 9. TPS565208 $V_{OUT} = 1.05\text{ V}$ Efficiency, $L = 2.2\text{ }\mu\text{H}$

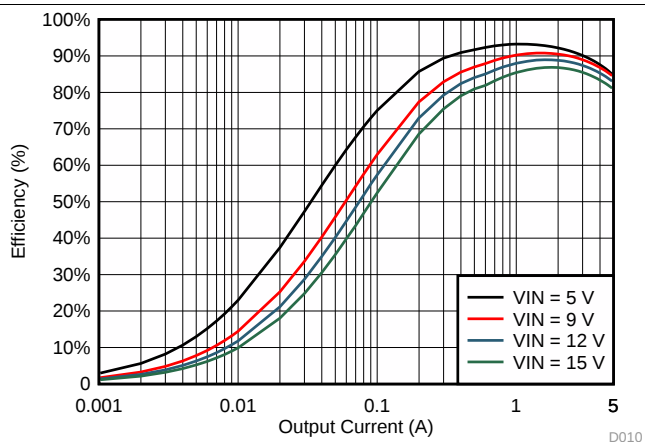


Figure 10. TPS565208 $V_{OUT} = 1.5\text{ V}$ Efficiency, $L = 2.2\text{ }\mu\text{H}$

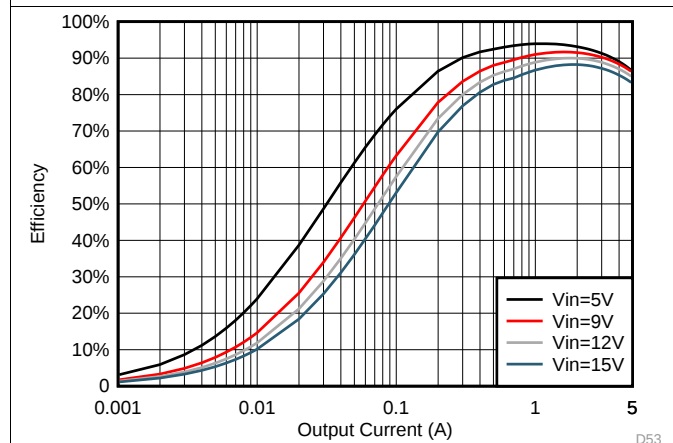


Figure 11. TPS565208 $V_{OUT} = 1.8\text{ V}$ Efficiency, $L = 2.2\text{ }\mu\text{H}$

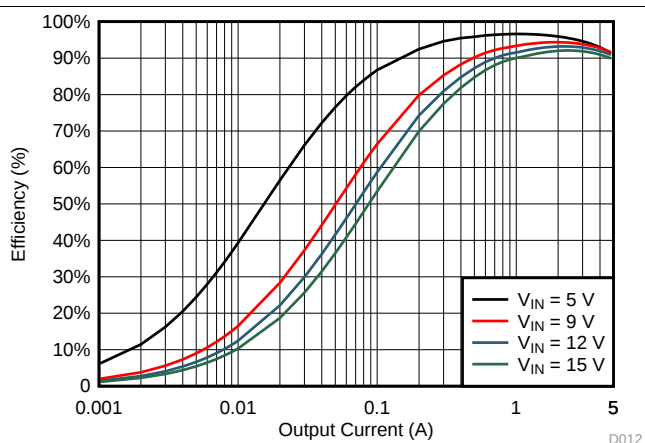
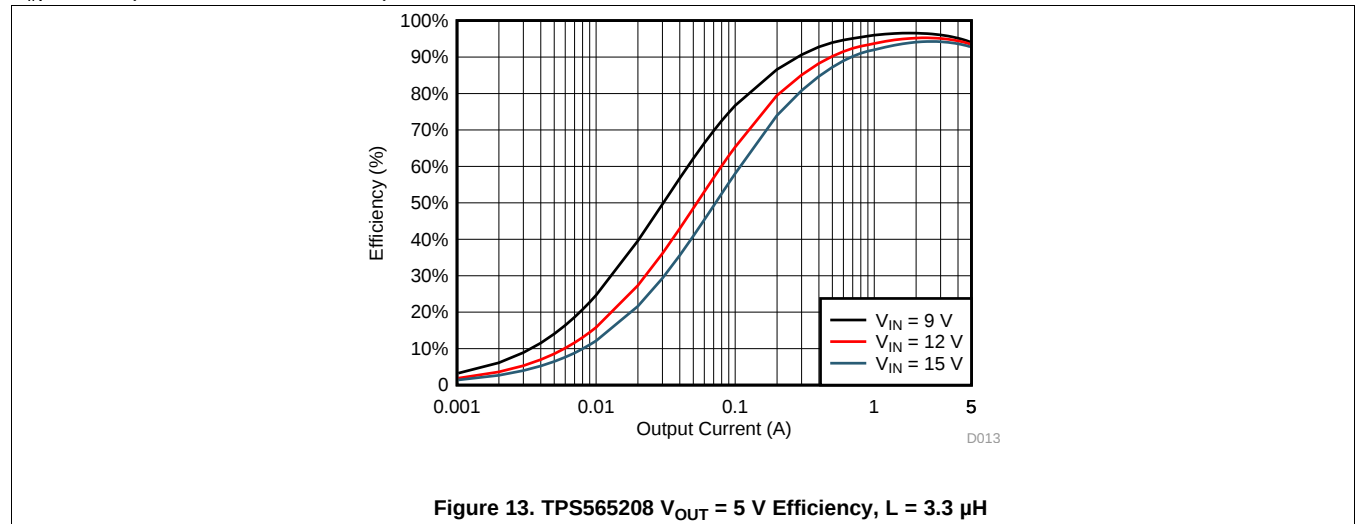


Figure 12. TPS565208 $V_{OUT} = 3.3\text{ V}$ Efficiency, $L = 2.2\text{ }\mu\text{H}$

Typical Characteristics (continued)

 $V_{IN} = 12\text{ V}$ (unless otherwise noted)


7.3 Feature Description

7.3.1 Adaptive On-Time Control and PWM Operation

The main control loop of the TPS565208 is adaptive on-time pulse width modulation (PWM) controller that supports a proprietary D-CAP2™ mode control. The D-CAP2™ mode control combines adaptive on-time control with an internal compensation circuit for pseudo-fixed frequency and low external component count configuration with low-ESR ceramic output capacitors. It is stable even with virtually no ripple at the output.

At the beginning of each cycle, the high-side MOSFET is turned on. This MOSFET is turned off after internal one-shot timer expires. This one shot duration is set inversely proportional to the converter input voltage, V_{IN} , and proportional to the output voltage V_O , to maintain a pseudo-fixed frequency over the input voltage range, hence it is called adaptive on-time control. The one-shot timer is reset and the high-side MOSFET is turned on again when the feedback voltage falls below the reference voltage. An ripple is added to reference voltage to simulate output ripple, eliminating the need for ESR induced output ripple from D-CAP2™ mode control.

7.3.2 Soft Start and Pre-Biased Soft Start

The TPS565208 has an internal 1.0-ms soft-start. When the EN pin becomes high, the internal soft-start function begins ramping up the reference voltage to the PWM comparator.

If the output capacitor is pre-biased at startup, the device initiates switching and starts ramping up only after the internal reference voltage becomes greater than the feedback voltage V_{FB} . This scheme ensures that the converter ramps up smoothly into regulation point.

7.3.3 Current Protection

The output over-current limit (OCL) is implemented using a cycle-by-cycle valley detect control circuit. The inductor current is monitored during the OFF state by measuring the low-side FET drain to source voltage. This voltage is proportional to the switch current. To improve accuracy, the voltage sensing is temperature compensated.

During the on time of the high-side FET switch, the switch current increases at a linear rate determined by V_{IN} , V_{OUT} , and the output inductor value. During the on time of the low-side FET switch, this current decreases linearly. The average value of the switch current is the load current I_{OUT} . If the monitored current is above the OCL level, the converter maintains low-side FET on and delays the creation of a new set pulse, even the voltage feedback loop requires one, until the current level becomes OCL level or lower. In subsequent switching cycles, the on-time is set to a fixed value and the current is monitored in the same manner.

There are some important considerations for this type of over-current protection. The load current is higher than the over-current threshold by one half of the peak-to-peak inductor ripple current. Also, when the current is being limited, the output voltage tends to fall as the demanded load current may be higher than the current available from the converter. This may cause the output voltage to fall. When the V_{FB} voltage falls below the UVP threshold voltage, the UVP comparator detects it. And then, the device shuts down after the UVP delay time (typically 24 μ s) and re-starts after the hiccup time (typically 14.9 ms).

When the over current condition is removed, the output voltage returns to the regulated value.

7.3.4 Undervoltage Lockout (UVLO) Protection

UVLO protection monitors the internal regulator voltage. When the voltage is lower than UVLO threshold voltage, the device is shut off. This protection is non-latching.

7.3.5 Thermal Shutdown

The device monitors the temperature of itself. If the temperature exceeds the threshold value (typically 172°C), the device is shut off. This is a non-latch protection.

7.4 Device Functional Modes

7.4.1 Normal Operation

When the input voltage is above the UVLO threshold and the EN voltage is above the enable threshold, the TPS565208 operates in the normal switching mode. Normal continuous conduction mode (CCM) occurs when the minimum switch current is above 0 A. In CCM, the TPS565208 operates at a quasi-fixed frequency of 550 kHz.

7.4.2 Standby Operation

When the TPS565208 is operating in normal CCM, it may be placed in standby by asserting the EN pin low.

Typical Application (continued)

8.2.1 Design Requirements

Table 1 shows the design parameters for this application.

Table 1. Design Parameters

PARAMETER	EXAMPLE VALUE
Input voltage range	4.5 to 17 V
Output voltage	1.05 V
Transient response, 1A/us slew rate	$\Delta V_{out} = \pm 5\%$
Input ripple voltage	400 mV
Output ripple voltage	20 mV
Output current rating	5 A
Operating frequency	550 kHz

8.2.2 Detailed Design Procedure

8.2.2.1 Custom Design With WEBENCH® Tools

Click [here](#) to create a custom design using the TPS565208 device with the WEBENCH® Power Designer.

1. Start by entering the input voltage (V_{IN}), output voltage (V_{OUT}), and output current (I_{OUT}) requirements.
2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at www.ti.com/WEBENCH.

8.2.2.2 Output Voltage Resistors Selection

The output voltage is set with a resistor divider from the output node to the VFB pin. TI recommends to use 1% tolerance or better divider resistors. Start by using to calculate V_{OUT} .

To improve efficiency at very light loads consider using larger value resistors. However, using too high of resistance causes the circuit to be more susceptible to noise; and, voltage errors from the VFB input current will be more noticeable.

$$V_{OUT} = 0.760 \times \left(1 + \frac{R1}{R2} \right) \quad (1)$$

8.2.2.3 Output Filter Selection

The LC filter used as the output filter has double pole at:

$$f_p = \frac{1}{2\pi\sqrt{L_{OUT} \times C_{OUT}}} \quad (2)$$

At low frequencies, the overall loop gain is set by the output set-point resistor divider network and the internal gain of the device. The low frequency phase is 180°. At the output filter pole frequency, the gain rolls off at a –40 dB per decade rate and the phase drops rapidly. D-CAP2 introduces a high frequency zero that reduces the gain roll off to –20 dB per decade and increases the phase to 90° one decade above the zero frequency. The inductor and capacitor for the output filter must be selected so that the double pole of Equation 2 is located below the high frequency zero but close enough that the phase boost provided by the high frequency zero provides adequate phase margin for a stable circuit. To meet this requirement use the values recommended in Table 2.

Table 2. Recommended Component Values

OUTPUT VOLTAGE (V)	R1 (kΩ)	R2 (kΩ)	L1 (μH)			C8 + C9 (μF)
			MIN	TYP	MAX	
1	3.09	10.0	1	2.2	4.7	20 to 68
1.05	3.74	10.0	1	2.2	4.7	20 to 68
1.2	5.76	10.0	1	2.2	4.7	20 to 68
1.5	9.53	10.0	1.5	2.2	4.7	20 to 68
1.8	13.7	10.0	1.5	2.2	4.7	20 to 68
2.5	22.6	10.0	2.2	2.2	4.7	20 to 68
3.3	33.2	10.0	2.2	2.2	4.7	20 to 68
5	54.9	10.0	3.3	3.3	4.7	20 to 68
6.5	75	10.0	3.3	3.3	4.7	20 to 68

The inductor peak-to-peak ripple current, peak current and RMS current are calculated using Equation 3, Equation 4, and Equation 5. The inductor saturation current rating must be greater than the calculated peak current and the RMS or heating current rating must be greater than the calculated RMS current.

Use 550 kHz for f_{SW} . Make sure the chosen inductor is rated for the peak current of Equation 4 and the RMS current of Equation 6.

$$I_{P-P} = \frac{V_{OUT}}{V_{IN(MAX)}} \times \frac{V_{IN(MAX)} - V_{OUT}}{L_O \times f_{SW}} \quad (3)$$

$$I_{PEAK} = I_O + \frac{I_{P-P}}{2} \quad (4)$$

$$I_{LO(RMS)} = \sqrt{I_O^2 + \frac{1}{12} I_{P-P}^2} \quad (5)$$

For this design example, the calculated peak current is 5.4 A and the calculated RMS current is 5 A. The inductor used is a WE 744311220 with a peak current rating of 13 A and an RMS current rating of 9 A.

The capacitor value and ESR determines the amount of output voltage ripple. The TPS565208 is intended for use with ceramic or other low ESR capacitors. Recommended values range from 20 μF to 68 μF. Use Equation 6 to determine the required RMS current rating for the output capacitor.

$$I_{CO(RMS)} = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{\sqrt{12} \times V_{IN} \times L_O \times f_{SW}} \quad (6)$$

For this design two TDK C3216X5R0J226M 22-μF output capacitors are used. The typical ESR is 2 mΩ each. The calculated RMS current is 0.229 A.

8.2.2.4 Input Capacitor Selection

The TPS565208 requires an input decoupling capacitor and a bulk capacitor is needed depending on the application. TI recommends a ceramic capacitor over 10 μF for the decoupling capacitor. An additional 0.1-μF capacitor (C3) from pin 3 to ground is optional to provide additional high frequency filtering. The capacitor voltage rating needs to be greater than the maximum input voltage.

8.2.2.5 Bootstrap Capacitor Selection

A 0.1- μ F ceramic capacitor must be connected between the VBST to SW pin for proper operation. TI recommends to use a ceramic capacitor.

8.2.3 Application Curves

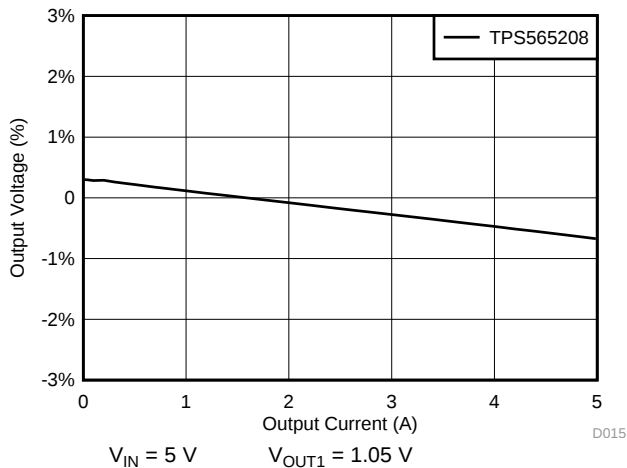


Figure 15. TPS565208 Load Regulation, $V_{IN} = 5\text{ V}$

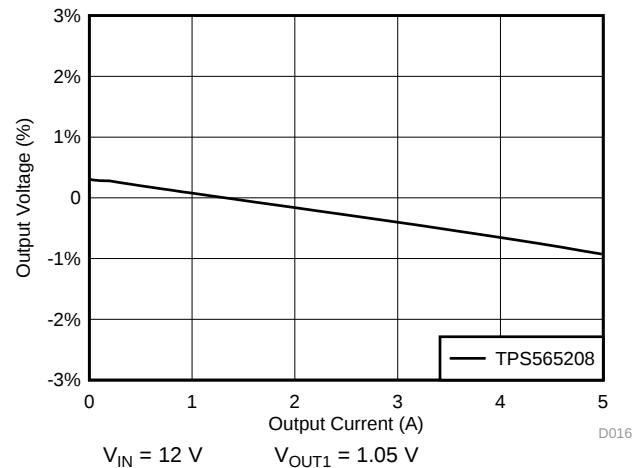


Figure 16. TPS565208 Load Regulation, $V_{IN} = 12\text{ V}$

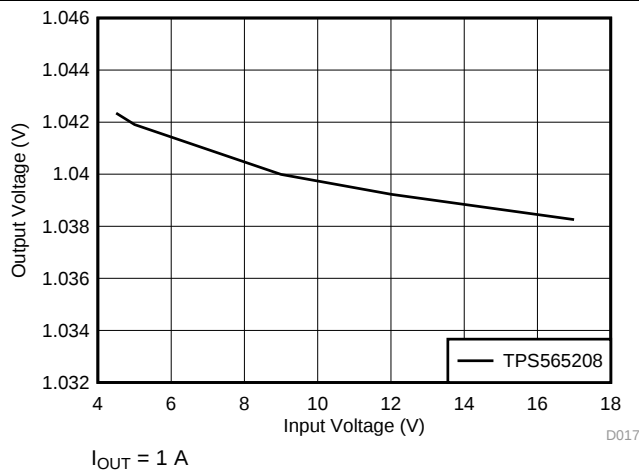


Figure 17. TPS565208 Line Regulation

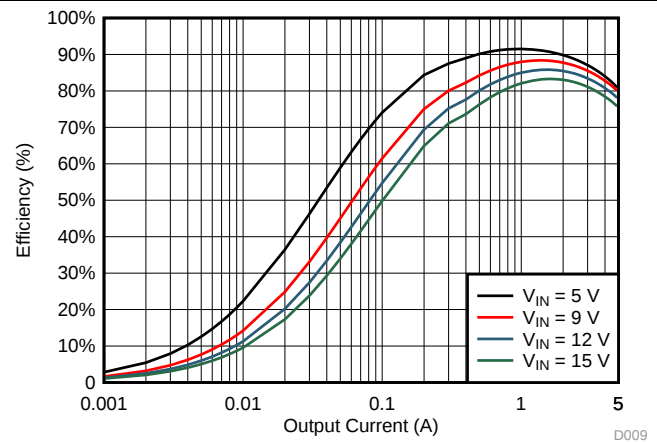


Figure 18. TPS565208 Efficiency, $V_{out} = 1.05\text{ V}$

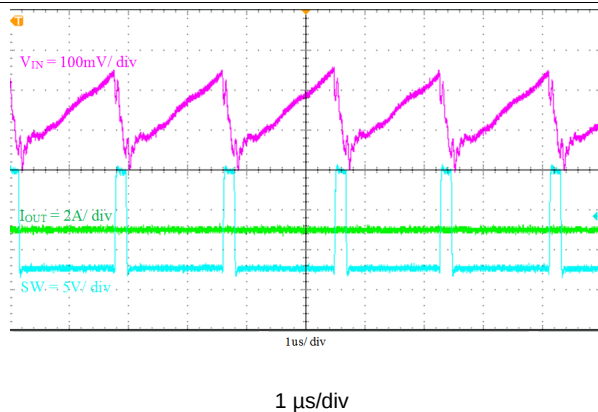


Figure 19. TPS565208 Input Voltage Ripple

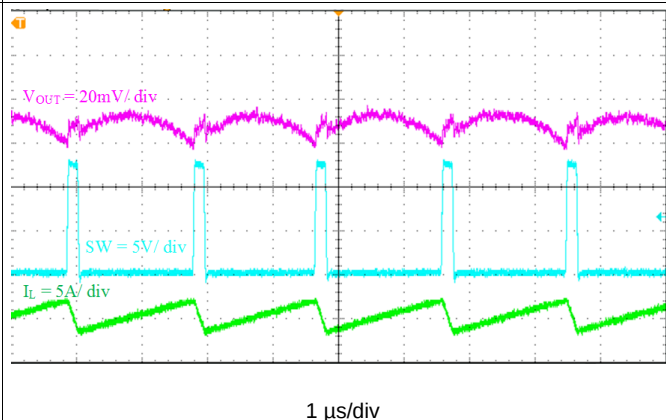
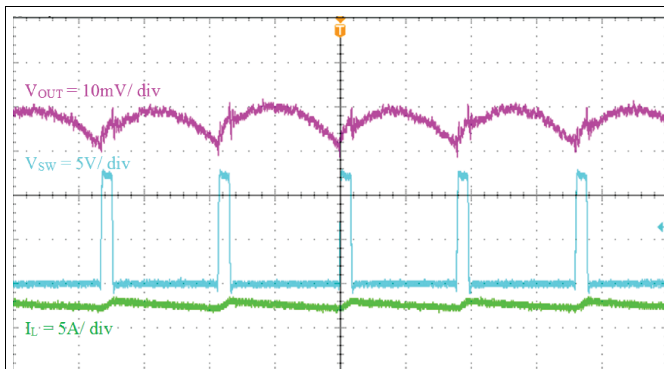
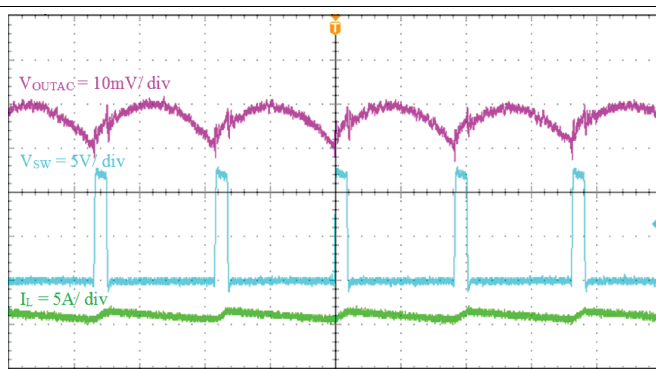


Figure 20. TPS565208 Output Voltage Ripple, No Load



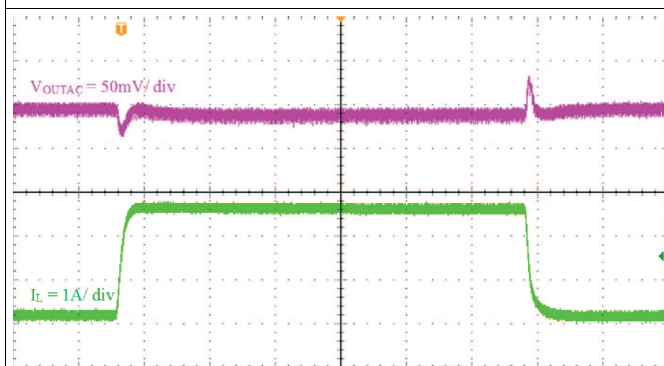
1 μ s/div

Figure 21. TPS565208 Output Voltage Ripple, I_{OUT} 2.5 A



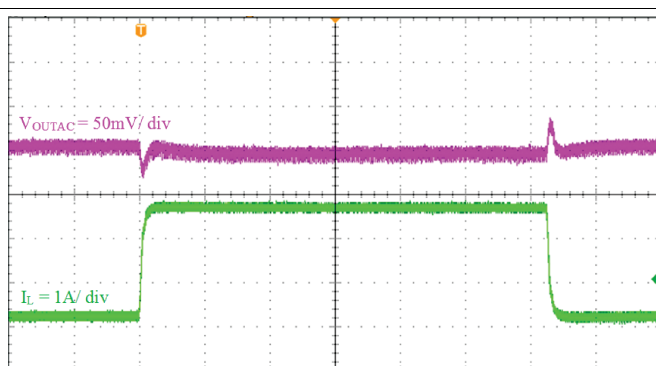
1 μ s/div

Figure 22. TPS565208 Output Voltage Ripple, I_{OUT} 5 A



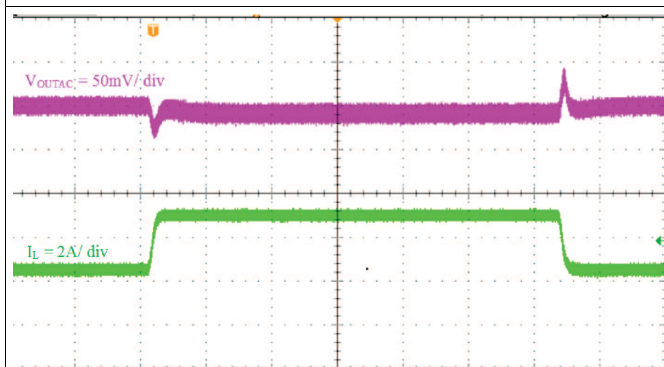
100 μ s/div

Figure 23. TPS565208 Transient Response 0.1 to 2.5 A



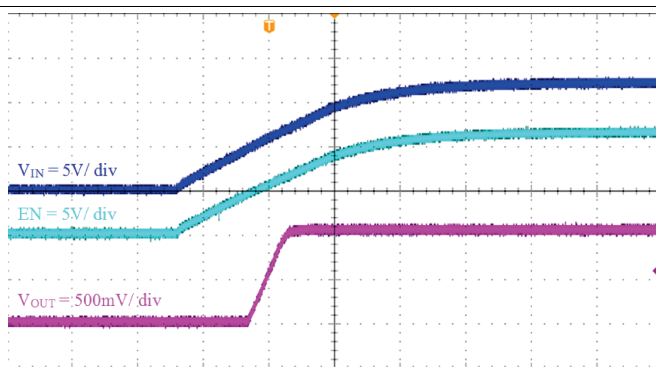
100 μ s/div

Figure 24. TPS565208 Transient Response, 1.25 to 3.75 A



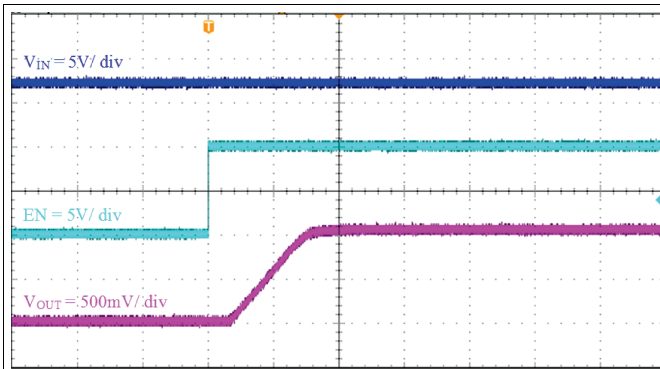
100 μ s/div

Figure 25. TPS565208 Transient Response, 2.5 to 5 A

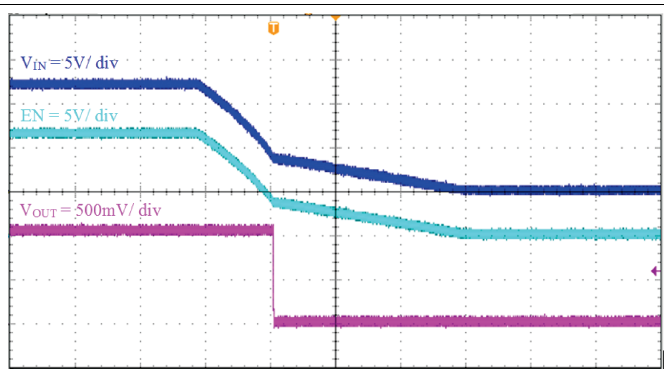


2 ms/div

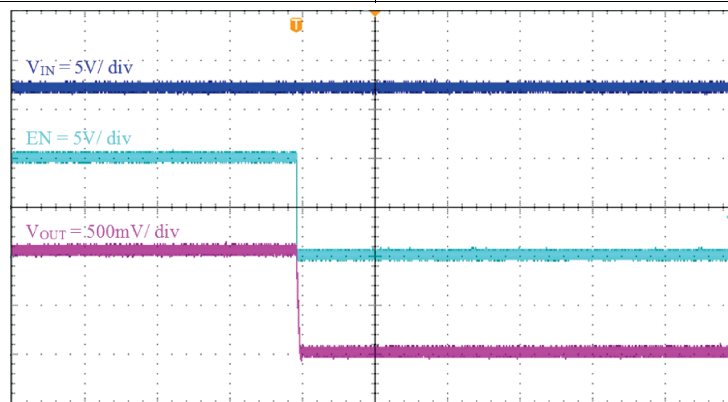
Figure 26. TPS565208 Startup Relative to V_{IN}



400 μs/div

Figure 27. TPS565208 Startup Relative to EN


20 ms/div

Figure 28. TPS565208 Shutdown Relative to V_{IN}


400 μs/div

Figure 29. TPS565208 Shutdown Relative to EN

9 Power Supply Recommendations

The TPS565208 is designed to operate from input supply voltage in the range of 4.5 V to 17 V. Buck converters require the input voltage to be higher than the output voltage for proper operation. The maximum recommended operating duty cycle is 83%. Using that criteria, the minimum recommended input voltage is $V_O / 0.83$.

10 Layout

10.1 Layout Guidelines

1. VIN and GND traces should be as wide as possible to reduce trace impedance. The wide areas are also of advantage from the view point of heat dissipation.
2. The input capacitor and output capacitor should be placed as close to the device as possible to minimize trace impedance.
3. Provide sufficient vias for the input capacitor and output capacitor.
4. Keep the SW trace as physically short and wide as practical to minimize radiated emissions.
5. Do not allow switching current to flow under the device.
6. A separate VOUT path should be connected to the upper feedback resistor.
7. Make a Kelvin connection to the GND pin for the feedback path.
8. Voltage feedback loop should be placed away from the high-voltage switching trace, and preferably has ground shield.
9. The trace of the VFB node should be as small as possible to avoid noise coupling.
10. The GND trace between the output capacitor and the GND pin should be as wide as possible to minimize its trace impedance.

10.2 Layout Example

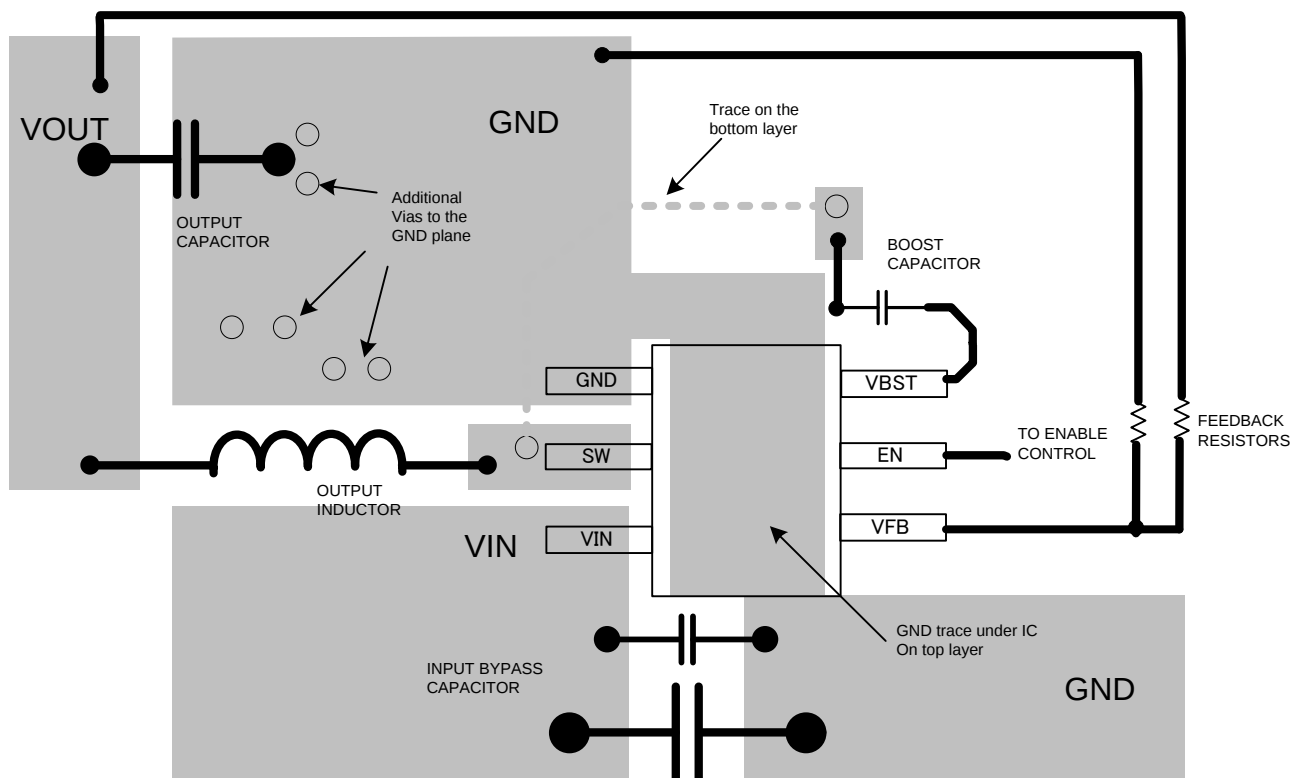


Figure 30. TPS565208 Layout Example

11 Device and Documentation Support

11.1 Development Support

11.1.1 Custom Design With WEBENCH® Tools

[Click here](#) to create a custom design using the TPS565208 device with the WEBENCH® Power Designer.

1. Start by entering the input voltage (V_{IN}), output voltage (V_{OUT}), and output current (I_{OUT}) requirements.
2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at www.ti.com/WEBENCH.

11.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.4 Trademarks

D-CAP2, E2E are trademarks of Texas Instruments.

WEBENCH is a registered trademark of Texas Instruments.

Blu-ray is a trademark of Blu-ray Disc Association.

11.5 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.6 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS565208DDCR	ACTIVE	SOT-23-THIN	DDC	6	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	5208	Samples
TPS565208DDCT	ACTIVE	SOT-23-THIN	DDC	6	250	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	5208	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS565208DDCR	SOT-23-THIN	DDC	6	3000	180.0	9.5	3.17	3.1	1.1	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS

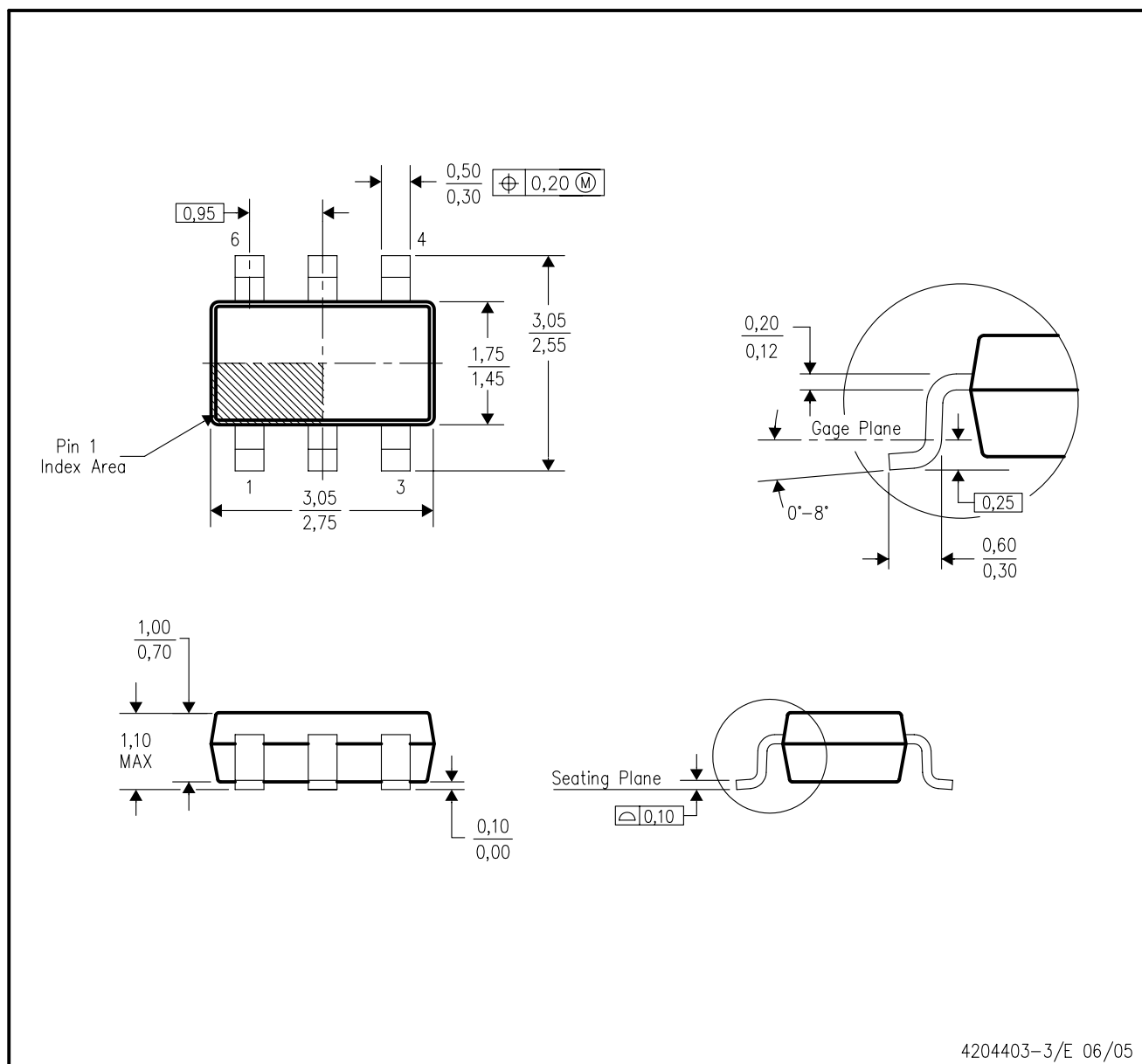


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS565208DDCR	SOT-23-THIN	DDC	6	3000	184.0	184.0	19.0

DDC (R-PDSO-G6)

PLASTIC SMALL-OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion.
 - D. Falls within JEDEC MO-193 variation AA (6 pin).

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